

### 40V 60A N-Channel Enhancement Mode Power MOSFET

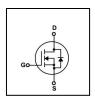
#### **Features**

- RDSON $\leq$ 10.5m  $\Omega$  @Vgs=10V, Id=10A
- · Advanced trench technology
- Excellent RDS(ON) and Low Gate Charge
- · Lead free product is acquired

### **Application**

- Load Switch
- PWM Application
- DC/DC Converter
- · High Frequency Switching

#### **SYMBOL**





TO-252

#### **ASSEMBLY MESSAGE**

Product Name	Package	Packaging
BXT105N04D	TO-252	Reel

## ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating TO-252	Unit
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Drain Current	Continuous (T <sub>C</sub> = 25°C)	l <sub>D</sub>	60	Α
Drain Current	Continuous (T <sub>C</sub> = 100°C)		32.5	Α
Drain Current	ent Pulsed (Note1)		240	Α
Single Pulsed Avalanche	Energy	EAS	70	mJ
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Power Dissipation	T <sub>C</sub> =25°C	PD	60	W
Maximum Junction Temperature		TJ	150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 to 150	°C

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	Unit	
Parameter	Syllibol	TO-252	Oill	
Thermal Resistance, Junction to Case	Rejc	2.08	°C / W	

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## **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub>=25°C,unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	VGS=0V, ID=250µA	40			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	VDS=40V, VGS=0V			1	uA
Gate-Body Leakage Current, Forward		VGS=20V			100	nA
Gate-Body Leakage Current, Reverse	Igss	VGS=-20V			-100	nA
ON CHARACTERISTICS			•	•	•	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	VDS=VGS, ID=250μA	1.0		2.5	V
Drain-Source On-State Resistance	В	VGS=10V, ID=10A		8.2	10.5	mΩ
Diam-Source On-State Resistance	$R_{DS(ON)}$	VGS=4.5V, ID=5A		9.8	12	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	Ciss	VDS=20V, VGS=0V,		910		pF
Output Capacitance	Coss			152		pF
Reverse Transfer Capacitance	Crss	f=1.0MHz		10.5		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t <sub>D(ON)</sub>			6		ns
Turn-ON Rise Time	t <sub>R</sub>	VDD=20V, ID=20A, VGS = 10V, RG=3Ω		9		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			30		ns
Turn-OFF Fall-Time	t <sub>F</sub>	1		5		ns
Total Gate Charge(Note2)	$Q_{\mathrm{G}}$	VDC 00V VCC 40V ID		13		nC
Gate Source Charge	Q <sub>GS</sub>	VDS =20V, VGS =10V, ID		3		nC
Gate Drain Charge	Q <sub>GD</sub>	=20A		2		nC
SOURCE- DRAIN DIODE RATINGS	AND CHAR	ACTERISTICS	•	•		
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	Is=10A, VGS=0V			1.4	V
Diode Continuous Forward Current	ls				60	Α
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				240	Α
Body Diode Reverse Recovery Time	trr			18		ns
Body Diode Reverse Recovery Charge	Qrr	IF=20A, dI/dt=100A/μs		9		nC

Note: 2. Essentially independent of operating temperature



#### TYPICAL CHARACTERISTICS

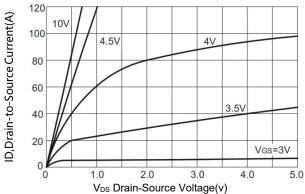


Figure 1. Typical Output Characteristics

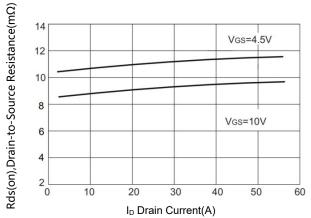


Figure 3. On-Resistance versus Drain Current

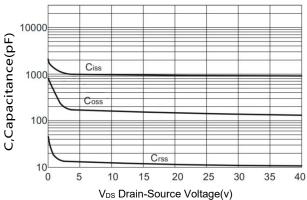


Figure 5. Typical Capacitance versus V<sub>DS</sub>

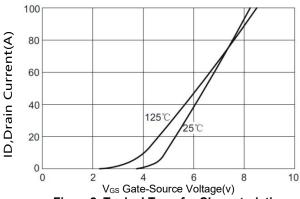


Figure 2. Typical Transfer Characteristics

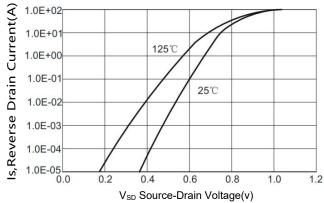


Figure 4. Diode forward voltage versus Current

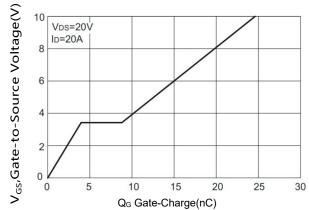


Figure 6. Typical Gate Charge versus V<sub>GS</sub>



# **TYPICAL CHARACTERISTICS(Cont.)**

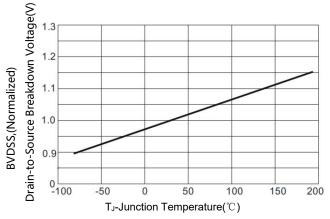


Figure 7. BV<sub>DSS</sub> Variation with Temperature

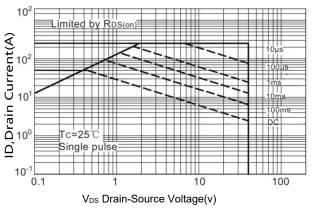


Figure9. Maximum Safe Operating Area

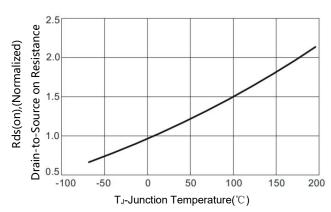


Figure 8. On-Resistance Variation with Temperature

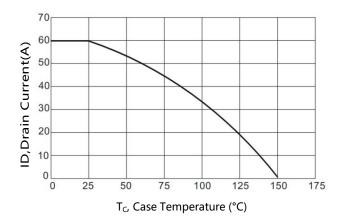
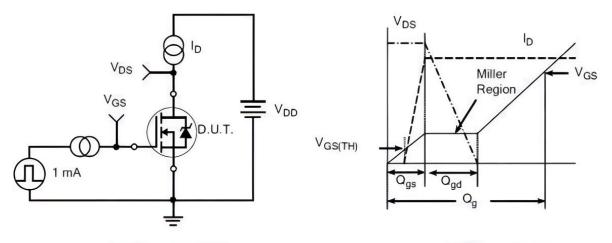


Figure 10. Maximum Continuous Drain Current versus Case Temperature

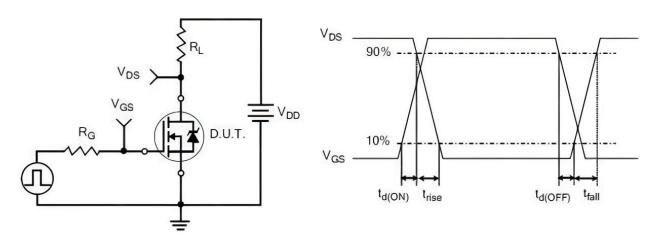


# **TEST CIRCUITS AND WAVEFORMS**





Gate Charge Waveform

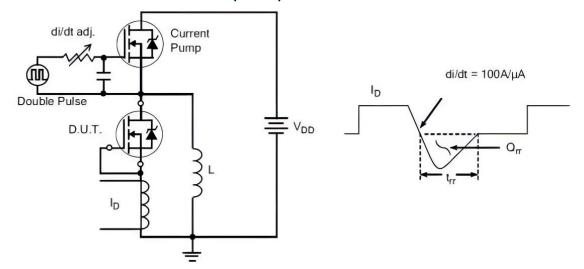


Resistive Switching Test Circuit

Resistive Switching Waveforms

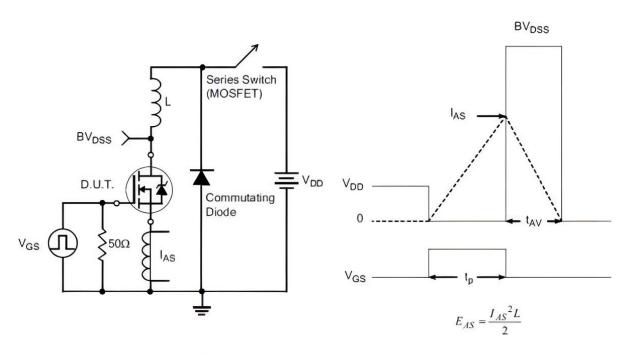


# **TEST CIRCUITS AND WAVEFORMS(Cont.)**



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



# **Revision history**

# **Document revision history**

Date	Revision	Changes
18-Sep-2021	1.0	First release

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